TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SG125AFS

### Bus Buffer with 3-STATE Output

#### **Features**

• High-level output current:  $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$ 

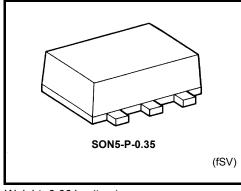
at V<sub>CC</sub> = 3.0 V

• High-speed operation: t<sub>pd</sub> = 2.4 ns (typ.)

at  $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$ 

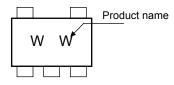
• Operating voltage range: V<sub>CC</sub> = 0.9~3.6 V

• 5.5-V tolerant inputs.

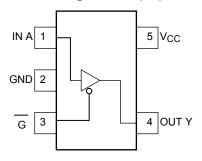


Weight: 0.001 g (typ.)

### Marking



### Pin Assignment (top view)



### **Absolute Maximum Ratings (Ta = 25°C)**

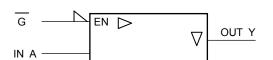
Characteristics	Symbol	Value	Unit
Power supply voltage	V <sub>CC</sub>	-0.5~4.6	V
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5~ V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	I <sub>OK</sub>	±20 (Note 1)	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	I <sub>CC</sub>	±50	mA
Power dissipation	PD	50	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>

### **IEC Logic Symbol**



### **Truth Table**

G	Α	Υ
Н	Х	Z
L	L	L
L	Н	Н

### **Operating Ranges**

Characteristics	Symbol	Value	Unit
Power supply voltage	V <sub>CC</sub>	0.9~3.6	V
Input voltage	V <sub>IN</sub>	0~5.5	V
Output voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
	I <sub>OH</sub> /I <sub>OL</sub>	±8.0 (Note 2)	
		±4.0 (Note 3)	
Output Current		±3.0 (Note 4)	mA
Output Current		±1.7 (Note 5)	IIIA
		±0.3 (Note 6)	
		±0.02 (Note 7)	
Operating temperature	T <sub>opr</sub>	-40~85	°C
Input rise and fall time	dt/dV	0~10 (Note 8)	ns/V

Note 2:  $V_{CC} = 3.0 \sim 3.6 \text{ V}$ 

Note 3:  $V_{CC} = 2.3 \sim 2.7 \text{ V}$ 

Note 4:  $V_{CC} = 1.65 \sim 1.95 \text{ V}$ 

Note 5:  $V_{CC} = 1.4 \sim 1.6 \text{ V}$ 

Note 6:  $V_{CC} = 1.1 \sim 1.3 \text{ V}$ 

Note 7:  $V_{CC} = 0.9 V$ 

Note 8:  $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$ 

### **Electrical Characteristics**

### **DC Characteristics**

Characteristics		Cumbal	Toot	Ta = $25^{\circ}$ C Ta = $-40^{\circ}85^{\circ}$ C				0~85°C	Unit						
Onaraciensuce Syl		Symbol	rest	Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit				
					0.9	V <sub>CC</sub>	_	_	V <sub>CC</sub>	_					
			_		1.1~1.3	V <sub>CC</sub> × 0.7			V <sub>CC</sub> × 0.7						
	High level	V <sub>IH</sub>			1.4~1.6	V <sub>CC</sub> × 0.65	_	_	V <sub>CC</sub> × 0.65	_					
					1.65~ 1.95	V <sub>CC</sub> × 0.65	ı		V <sub>CC</sub> × 0.65						
					2.3~2.7	1.7	_	_	1.7	-					
Input voltage					3.0~3.6	2.0			2.0		V				
input voltage					0.9	_		GND	_	GND	v				
					1.1~1.3		ı	V <sub>CC</sub> × 0.3		V <sub>CC</sub> × 0.3					
	Low level	V <sub>IL</sub>		_	1.4~1.6			V <sub>CC</sub> × 0.35		V <sub>CC</sub> × 0.35					
					1.65~ 1.95			V <sub>CC</sub> × 0.35		V <sub>CC</sub> × 0.35					
					2.3~2.7	_	_	0.7	_	0.7					
						3.0~3.6	_		0.8	_	8.0				
		ih level V <sub>OH</sub>		I <sub>OH</sub> =-0.02 mA	0.9	0.75	_	_	0.75	_					
	High level			$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75						
			V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> ,	I <sub>OH</sub> = -1.7 mA	1.4~1.6	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_					
			or v <sub>IL</sub> ,	I <sub>OH</sub> = -3.0 mA	1.65~ 1.95	V <sub>CC</sub> -0.45	_	_	V <sub>CC</sub> -0.45	_					
					ļ				I <sub>OH</sub> = -4.0 mA	2.3~2.7	2.0	_	_	2.0	_
Output voltage				$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48	_	_	2.48		V				
Output voltage				$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	V				
				I <sub>OL</sub> = 0.3 mA	1.1~1.3	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25					
	Low level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 1.7 mA	1.4~1.6	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25					
				I <sub>OL</sub> = 3.0 mA	1.65~ 1.95		l	0.45		0.45					
				I <sub>OL</sub> = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4					
				I <sub>OL</sub> = 8.0 mA	3.0~3.6	_	_	0.4	_	0.4					
Input leakage curre	Input leakage current I <sub>I</sub>		V <sub>IN</sub> = 0~5.	.5V	0~3.6	_	_	±0.1	_	±1.0	μА				
3-state output off-s current	tate	l <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> V <sub>OUT</sub> = 0	or V <sub>IL</sub> , ~3.6 V	0.9~3.6	_		1.0	_	10.0	μА				
Quiescent supply of	current	Icc	$V_{IN} = V_{CC}$	or GND	3.6	_		1.0	_	10.0	μΑ				

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## AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Characteristics Symbol Test Condition V <sub>CC</sub> (V)			Ta = 25°0		Ta = -40~85°C		Unit	
Characteristics			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
			0.9	_	15.3	_	_	_	
			1.1~1.3	_	8.3	18.4	1.0	34.2	
		C <sub>L</sub> = 10 pF,	1.4~1.6	_	5.0	8.5	1.0	10.0	
		$R_L = 1 M\Omega$	1.65~ 1.95	_	4.0	6.2	1.0	6.7	
			2.3~2.7	_	2.6	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
			0.9	_	17.7	_	_	_	
			1.1~1.3		9.6	21.5	1.0	37.2	
Propagation delay time	t <sub>pLH</sub>	C <sub>L</sub> = 15 pF,	1.4~1.6	_	5.6	9.3	1.0	11.2	ne
Propagation delay time	t <sub>pHL</sub>	$R_L = 1 M\Omega$	1.65~ 1.95	_	4.5	6.9	1.0	7.1	ns
			2.3~2.7	_	2.9	4.4	1.0	5.0	
			3.0~3.6	_	2.4	3.4	1.0	3.9	
			0.9	_	29.0	_	_	_	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	1.1~1.3	_	14.5	29.6	1.0	56.0	
			1.4~1.6	_	8.2	13.1	1.0	15.9	
			1.65~ 1.95	_	6.0	9.2	1.0	9.6	
			2.3~2.7	_	4.0	5.7	1.0	6.1	
			3.0~3.6	_	3.3	4.4	1.0	4.8	
		$C_L = 10 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	18.9	_	_	_	ns
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.1~1.3	_	9.8	16.9	1.0	24.8	
			1.4~1.6	_	5.3	7.8	1.0	8.3	
			1.65~ 1.95	_	3.9	5.5	1.0	5.9	
			2.3~2.7	_	2.5	3.5	1.0	3.8	
			3.0~3.6	_	2.1	2.7	1.0	3.0	
		$C_L = 15 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	22.0	_	_	_	
			1.1~1.3	_	11.0	18.7	1.0	28.4	
Output enable time	t <sub>pZL</sub>		1.4~1.6	_	5.9	8.9	1.0	11.0	
	t <sub>pZH</sub>	$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	4.4	6.3	1.0	6.5	
			2.3~2.7	_	2.9	3.9	1.0	4.2	
			3.0~3.6	_	2.3	3.0	1.0	3.3	
		$C_L = 30 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	31.8	_	_	_	
			1.1~1.3	_	15.6	27.3	1.0	43.2	
			1.4~1.6	_	8.3	12.2	1.0	13.7	
		$C_L = 30 \text{ pF},$	1.65~ 1.95	_	6.1	8.6	1.0	9.7	
		$R_L = 5 \text{ k}\Omega$	2.3~2.7	_	3.8	5.0	1.0	5.5	
			3.0~3.6	_	2.9	3.8	1.0	4.2	

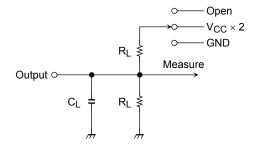
Characteristics	Symbol	Test Condition			Га = 25°C	)	Ta = -4	0~85°C	Unit		
Characteristics	Symbol	rest Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic		
		$C_L = 10 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	100.4	_	_	-			
			1.1~1.3	_	9.1	14.4	1.0	22.4			
			1.4~1.6	_	7.1	9.1	1.0	10.4			
		$C_L = 10 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	6.5	8.3	1.0	9.0			
		_	2.3~2.7	_	5.8	7.3	1.0	8.8			
			3.0~3.6	_	5.4	6.9	1.0	7.6			
	t <sub>pLZ</sub> t <sub>pHZ</sub>	$\begin{aligned} C_L &= 15 \text{ pF}, \\ R_L &= 100 \text{ k}\Omega \end{aligned}$	0.9	_	122.2	_	_				
Output disable time			1.1~1.3	_	9.8	15.3	1.0	25.1	ns		
			1.4~1.6	_	7.8	9.8	1.0	11.3			
			$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	$C_L = 15 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	7.2	9.2	1.0	10.6	
							2.3~2.7	_	7.0	8.2	1.0
			3.0~3.6	_	6.6	7.7	1.0	9.5			
		$C_L = 30 \text{ pF},$ $R_L = 100 \text{ k}\Omega$	0.9	_	217.1	_	_	_			
			1.1~1.3	_	13.2	19.6	1.0	31.9			
			1.4~1.6	_	12.2	13.5	1.0	14.9			
		$C_L = 30 \text{ pF},$ $R_L = 5 \text{ k}\Omega$	1.65~ 1.95	_	11.4	12.7	1.0	13.9			
			2.3~2.7	_	11.3	12.2	1.0	13.5			
			3.0~3.6		10.2	11.5	1.0	12.9			
Input capacitance	C <sub>IN</sub>	_	3.6	_	3	_	_	_	pF		
Power dissipation capacitance	C <sub>PD</sub>	(Note 9)	0.9 ~ 3.6		6	_	_	_	pF		

Note 9:C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

#### **AC Characteristics Measurement Circuit**



Characteristics	Switch
t <sub>pLH</sub> , t <sub>pHL</sub>	Open
t <sub>pLZ,</sub> t <sub>pZL</sub>	V <sub>CC</sub> × 2
t <sub>pHZ,</sub> t <sub>pZH</sub>	GND

 $Figure 1 \quad t_{pLH}, \, t_{pHL}$ 

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#### **AC Characteristics Measurement Circuit**

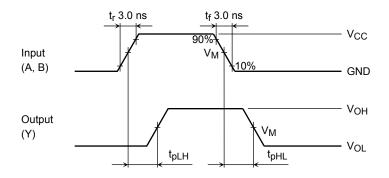


Figure2 t<sub>pLH</sub>, t<sub>pHL</sub>

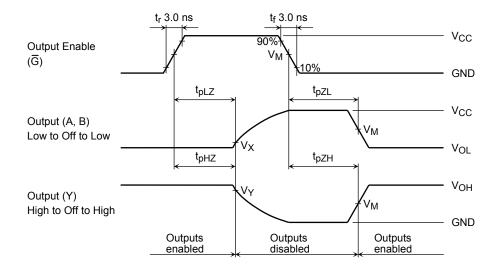


Figure 3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$ 

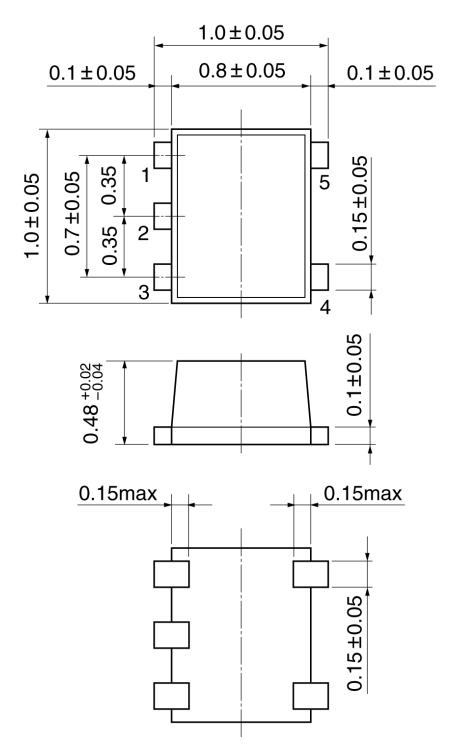
UNIT			Vo	CC		
OIVII	3.3±0.3 V	2.5±0.2 V	1.8±0.15 V	1.5±0.1 V	1.2±0.1 V	0.9 V
V <sub>M</sub>	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2
VX	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.1 V	V <sub>OL</sub> + 0.1 V	V <sub>OL</sub> + 0.1 V
VY	V <sub>OH</sub> - 0.3 V	V <sub>OH</sub> - 0.15 V	V <sub>OH</sub> - 0.15 V	V <sub>OH</sub> - 0.1 V	V <sub>OH</sub> - 0.1 V	V <sub>OH</sub> - 0.1 V

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### **Package Dimensions**

SON5-P-0.35 Unit:mm



Weight: 0.001 g (typ.)

### **RESTRICTIONS ON PRODUCT USE**

20070701-EN GENERAL

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